

## Trench Schottky Rectifier

### FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Low power loss/ high efficiency
- High forward surge capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition



**ITO-220AB**



### TYPICAL APPLICATIONS

Trench Schottky barrier rectifier are designed for high frequency miniature switched mode power supplies such as adapters, lighting and on-board DC/DC converters.

### MECHANICAL DATA

**Case:** ITO-220AB

Molding compound meets UL 94 V-0 flammability rating

Packing code with suffix "G" means green compound (halogen-free)

**Terminal:** Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 1A whisker test

**Polarity:** As marked

Mounting torque: 0.56 Nm max.

**Weight:** 1.7 g (approximately)

| MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25°C unless otherwise noted)   |                      |                        |                    |                |      |                |      |                |      |                |      |      |  |
|-------------------------------------------------------------------------------------------------|----------------------|------------------------|--------------------|----------------|------|----------------|------|----------------|------|----------------|------|------|--|
| PARAMETER                                                                                       |                      |                        | SYMBOL             | TSF40L<br>100C |      | TSF40L<br>120C |      | TSF40L<br>150C |      | TSF40L<br>200C |      | UNIT |  |
| Maximum repetitive peak reverse voltage                                                         |                      |                        | V <sub>RRM</sub>   | 100            |      | 120            |      | 150            |      | 200            |      | V    |  |
| Maximum average forward<br>rectified current                                                    | per device           |                        | I <sub>F(AV)</sub> | 40             |      |                |      |                |      |                |      | A    |  |
|                                                                                                 | per diode            |                        |                    | 20             |      |                |      |                |      |                |      |      |  |
| Peak forward surge current, 8.3ms single half<br>sine-wave superimposed on rated load per diode |                      |                        | I <sub>FSM</sub>   | 200            |      |                |      |                |      |                |      | A    |  |
| Voltage rate of change (Rated V <sub>R</sub> )                                                  |                      |                        | dV/dt              | 10000          |      |                |      |                |      |                |      | V/μs |  |
|                                                                                                 |                      |                        |                    | TYP            | MAX  | TYP            | MAX  | TYP            | MAX  | TYP            | MAX  |      |  |
| Instantaneous forward<br>voltage per diode (Note1)                                              | I <sub>F</sub> = 10A | T <sub>J</sub> = 25°C  | V <sub>F</sub>     | 0.60           | -    | 0.67           | -    | 0.77           | -    | 0.80           | -    | V    |  |
|                                                                                                 | I <sub>F</sub> = 20A |                        |                    | 0.72           | 0.80 | 0.79           | 0.85 | 0.86           | 0.96 | 0.88           | 0.98 |      |  |
|                                                                                                 | I <sub>F</sub> = 10A | T <sub>J</sub> = 125°C |                    | 0.54           | -    | 0.58           | -    | 0.64           | -    | 0.67           |      |      |  |
|                                                                                                 | I <sub>F</sub> = 20A |                        |                    | 0.65           | 0.73 | 0.69           | 0.77 | 0.74           | 0.82 | 0.76           | 0.84 |      |  |
| Instantaneous reverse current per<br>diode at rated reverse voltage                             |                      | T <sub>J</sub> = 25°C  | I <sub>R</sub>     |                | 250  | -              | 250  | -              | 100  | -              | 100  | μA   |  |
|                                                                                                 |                      | T <sub>J</sub> = 125°C |                    | 10             | 25   | 10             | 25   | 3              | 15   | 3              | 15   | mA   |  |
| Typical thermal resistance per diode                                                            |                      |                        | R <sub>θJC</sub>   | 3.5            |      |                |      | 4.5            |      |                |      | °C/W |  |
| Operating junction temperature range                                                            |                      |                        | T <sub>J</sub>     | - 55 to +150   |      |                |      |                |      |                |      | °C   |  |
| Storage temperature range                                                                       |                      |                        | T <sub>STG</sub>   | - 55 to +150   |      |                |      |                |      |                |      | °C   |  |

Note 1: Pulse test with pulse width=300μs, 1% duty cycle

| ORDERING INFORMATION    |              |                     |           |           |
|-------------------------|--------------|---------------------|-----------|-----------|
| PART NO.                | PACKING CODE | PACKING CODE SUFFIX | PACKAGE   | PACKING   |
| TSF40LXXXXC<br>(Note 1) | C0           | G                   | ITO-220AB | 50 / Tube |

Note 1: "XXX" defines voltage from 100V (TSF40L100C) to 200V (TSF40L200C)

| EXAMPLE            |            |              |                     |                |
|--------------------|------------|--------------|---------------------|----------------|
| PREFERRED PART NO. | PART NO.   | PACKING CODE | PACKING CODE SUFFIX | DESCRIPTION    |
| TSF40L120C C0G     | TSF40L120C | C0           | G                   | Green compound |

## RATINGS AND CHARACTERISTICS CURVES

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

FIG. 1 FORWARD CURRENT DERATING CURVE

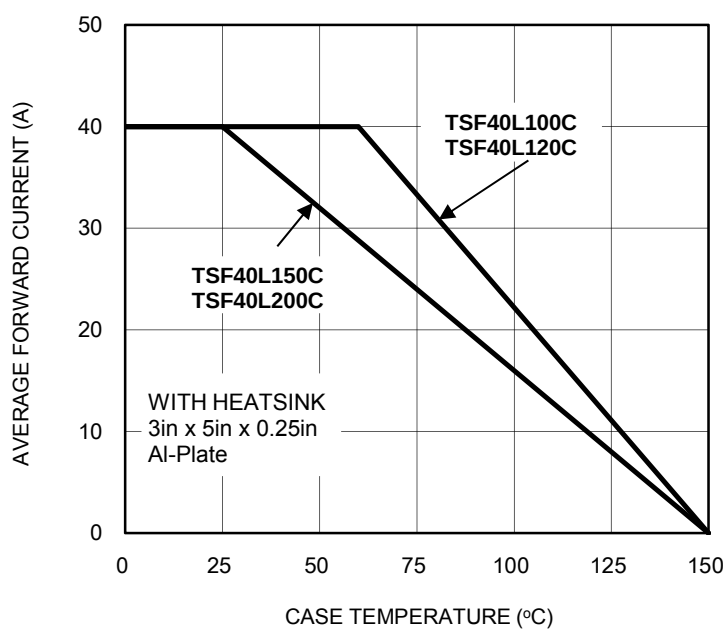


FIG. 2 TYPICAL FORWARD CHARACTERISTICS

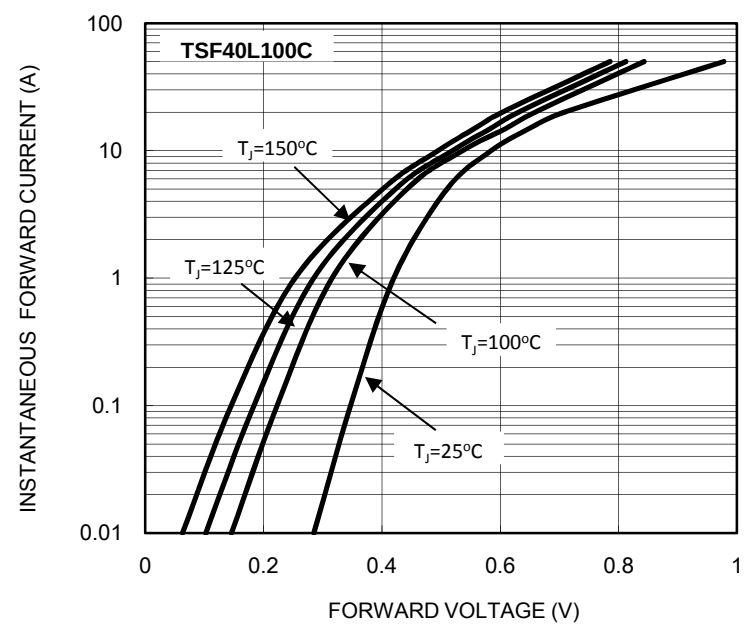


FIG. 3 TYPICAL FORWARD CHARACTERISTICS

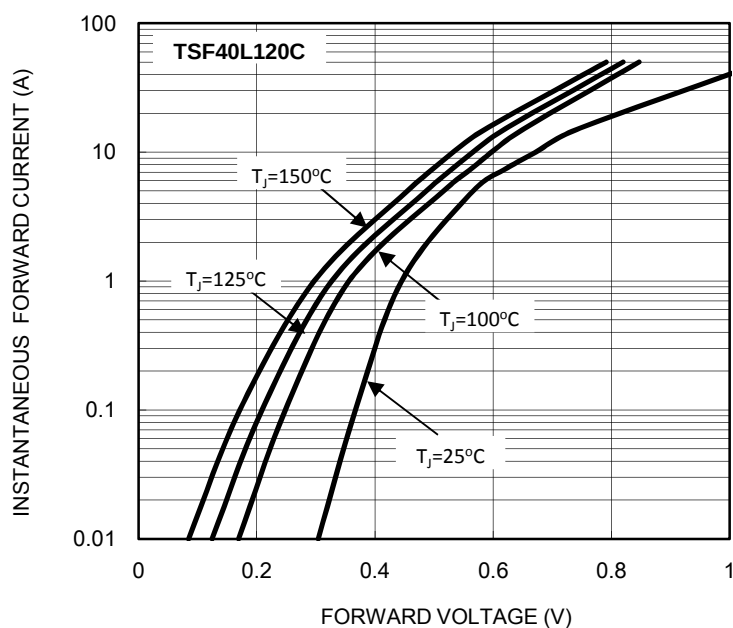


FIG. 4 TYPICAL FORWARD CHARACTERISTICS

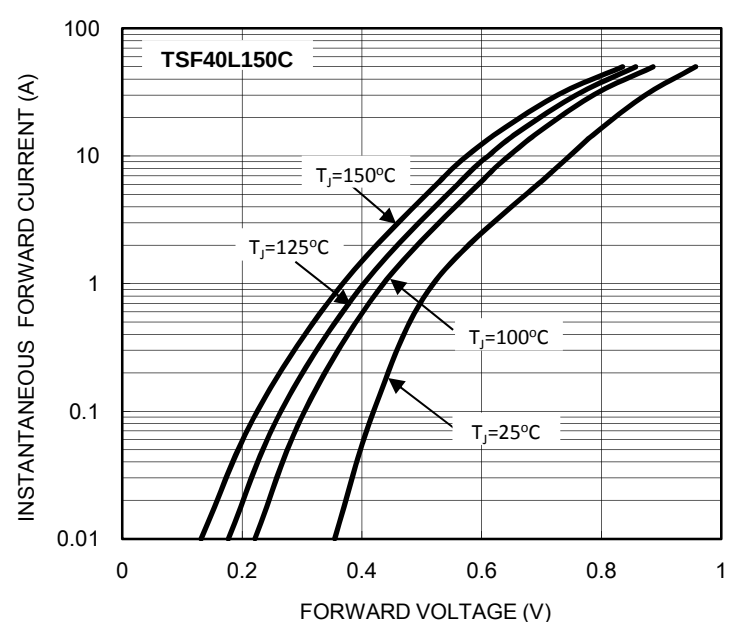


FIG. 5 TYPICAL FORWARD CHARACTERISTICS

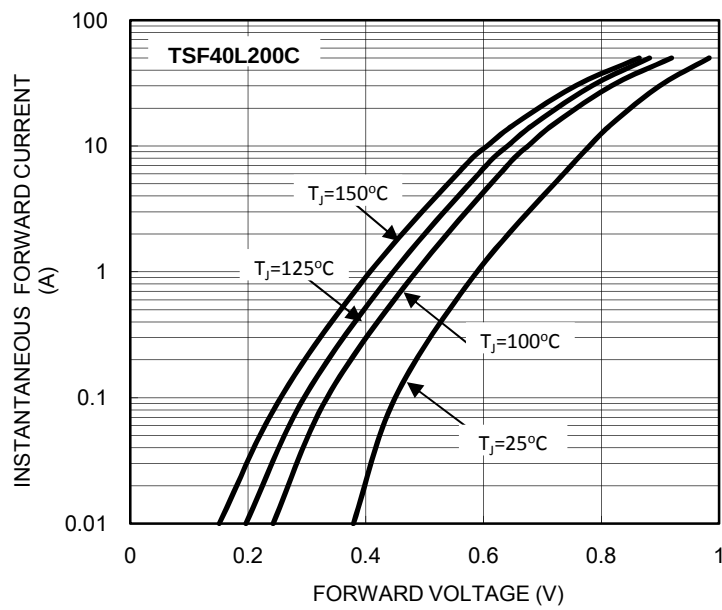


FIG. 6 TYPICAL REVERSE CHARACTERISTICS

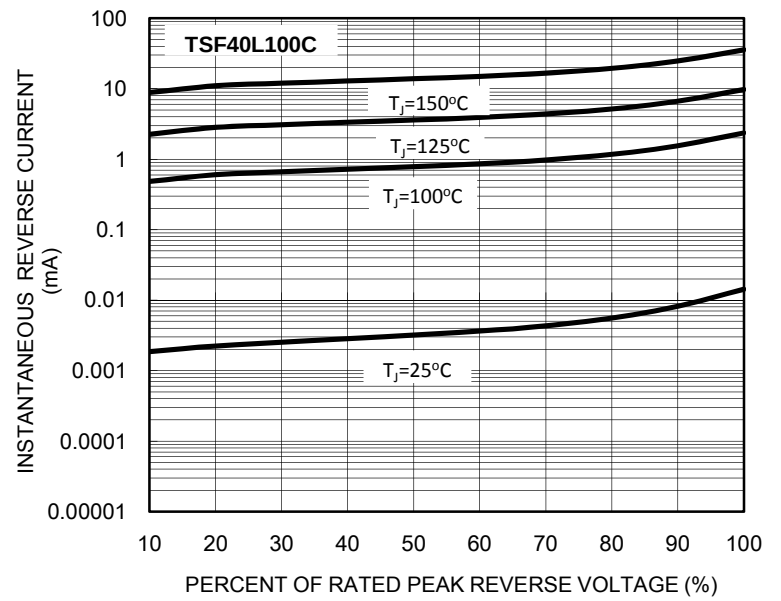


FIG. 7 TYPICAL REVERSE CHARACTERISTICS

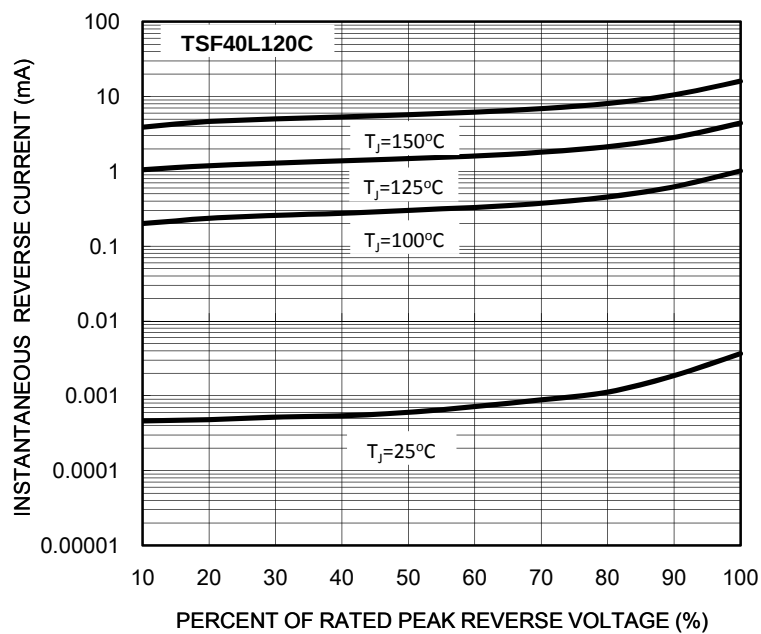


FIG. 8 TYPICAL REVERSE CHARACTERISTICS

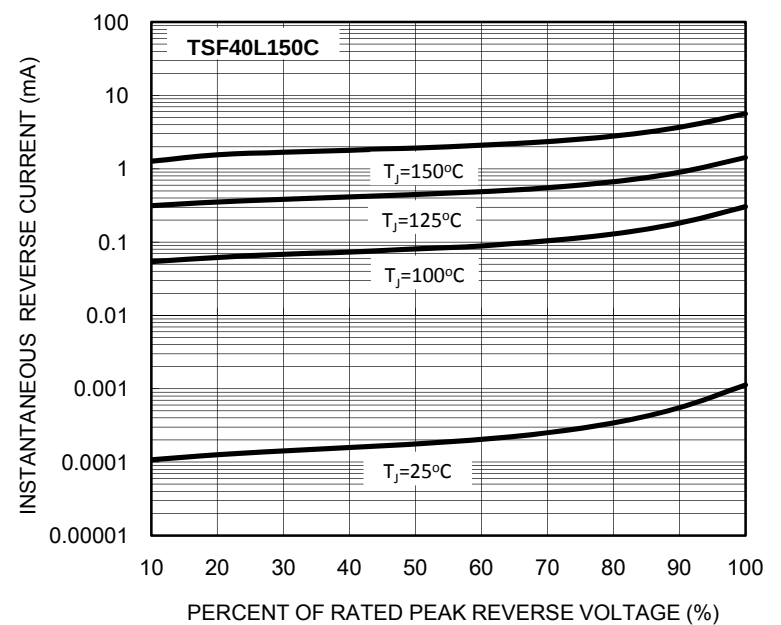


FIG. 9 TYPICAL REVERSE CHARACTERISTICS

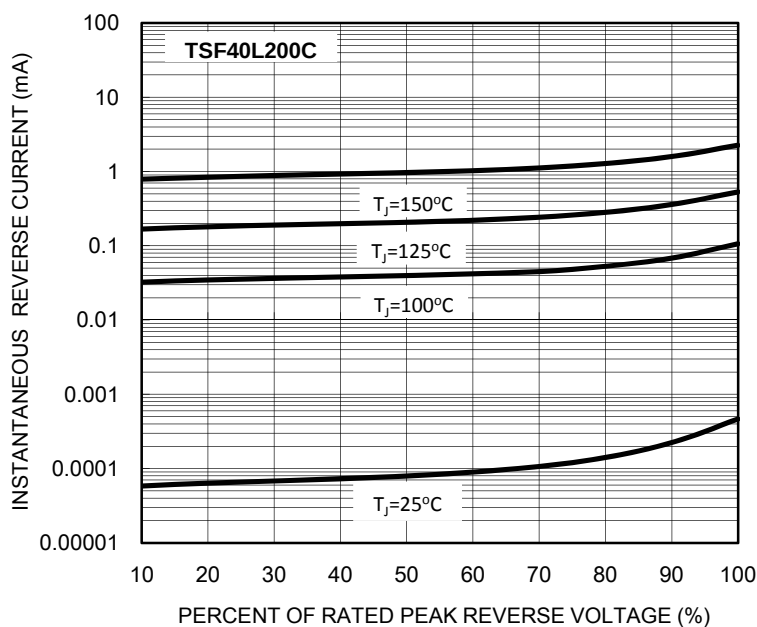
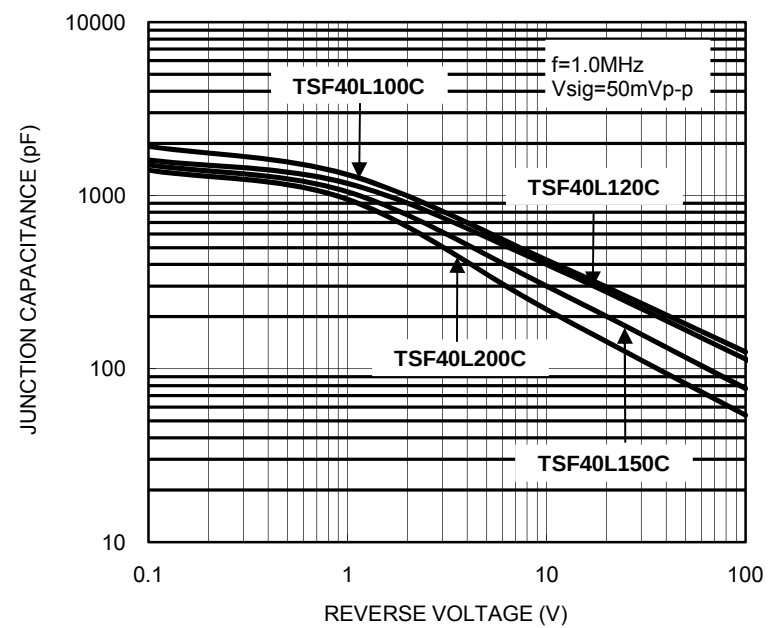
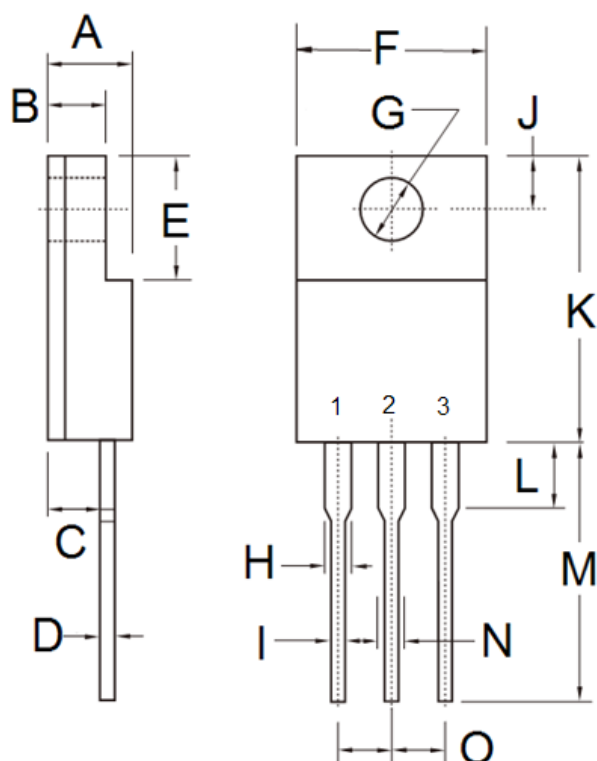


FIG. 10 TYPICAL JUNCTION CAPACTIANCE



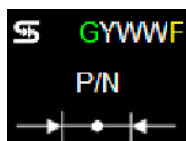
**PACKAGE OUTLINE DIMENSIONS**

ITO-220AB



| DIM. | Unit (mm) |       | Unit (inch) |      |
|------|-----------|-------|-------------|------|
|      | Min       | Max   | Min         | Max  |
| A    | 4.30      | 4.70  | 0.17        | 0.19 |
| B    | 2.50      | 3.16  | 0.10        | 0.12 |
| C    | 2.30      | 2.96  | 0.09        | 0.12 |
| D    | 0.46      | 0.76  | 0.02        | 0.03 |
| E    | 6.30      | 6.90  | 0.25        | 0.27 |
| F    | 9.60      | 10.30 | 0.38        | 0.41 |
| G    | 3.00      | 3.40  | 0.12        | 0.13 |
| H    | 0.95      | 1.45  | 0.04        | 0.06 |
| I    | 0.50      | 0.90  | 0.02        | 0.04 |
| J    | 2.40      | 3.20  | 0.09        | 0.13 |
| K    | 14.80     | 15.50 | 0.58        | 0.61 |
| L    | -         | 4.10  | -           | 0.16 |
| M    | 12.60     | 13.80 | 0.50        | 0.54 |
| N    | -         | 1.80  | -           | 0.07 |
| O    | 2.41      | 2.67  | 0.09        | 0.11 |

**MARKING DIAGRAM**



P/N = Specific Device Code  
G = Green Compound  
YWW = Date Code  
F = Factory Code

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